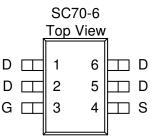
Analog Power AM1432NE

N-Channel 30V (D-S) MOSFET

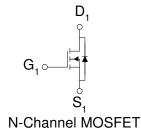
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

al applications are DC-DC	$V_{DS}(V)$	$\mathbf{r_{DS(on)}}\left(\Omega \right)$	$I_{D}(A)$
wer management in portable and roducts such as computers,	30	$0.033 @ V_{GS} = 10 V$	5.7
cards, cellular and cordless	30	$0.045 @ V_{GS} = 4.5V$	4.9
	0	D	

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SC70-6 saves board space
- Fast switching speed
- High performance trench technology



PRODUCT SUMMARY



Protected

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage		V_{DS}	30	V		
Gate-Source Voltage	V_{GS}	±20	V			
	$T_A=25^{\circ}C$	Ι,	5.7			
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1 _D	4.6	A		
Pulsed Drain Current ^b		I_{DM}	±20			
Continuous Source Current (Diode Conduction) ^a		I_S	1.6	A		
D D: a	$T_A=25^{\circ}C$	D	1.56	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	P_{D}	0.81	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	t <= 5 sec	D	100	0000	
	Steady-State	R_{THJA}	166	C/W	

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM1432NE

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Parameter	Cymbal	Treat Constitutions	Limits			T 124	
Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	μΑ	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate Voltage Drain Current	*D88	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10		
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			A	
D : G C D : A		$V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$			33	mΩ	
Drain-Source On-Resistance ^A	$r_{\mathrm{DS(on)}}$	$V_{GS} = 4.5 \text{ V}, I_{D} = 1 \text{ A}$			45	1112.2	
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ A}$		11.3		S	
Diode Forward Voltage	V_{SD}	$I_S = 1 A, V_{GS} = 0 V$		0.75		V	
Dynamic ^b							
Total Gate Charge	Q_{g}			4			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1 \text{ A}$		1		пC	
Gate-Drain Charge	Q_{gd}			1		1	
Turn-On Delay Time	$t_{d(on)}$	and the second s		4			
Rise Time	$t_{\rm r}$	$V_{DD} = 10 \text{ V}, R_L = 15 \Omega, I_D = 1 \text{ A},$		10			
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 4.5 \text{ V}$		20		ns	
Fall-Time	t_{f}			10		1	

Notes

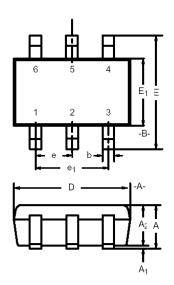
a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

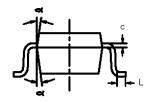
b. Guaranteed by design, not subject to production testing.

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Package Information

SC-70: 6LEAD





	MILLIMETERS			INCHES		
Dim	Min	Nom	Мах	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A ₁	_	_	0.10	_	_	0.004
A ₂	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	_	0.25	0.004	_	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC		0.026BSC			
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
4	7°Nom			7°Nom		